NSN 5961-00-139-6630

Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-139-6630 **Inclosure Material:** Metal **Overall Length:** 0.830 inches **End Application:** An/apq-148 radar; ea-6b prowler aircraft **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.250 inches **Thread Size:** 0.138 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 33.0 breakdown voltage, dc and 36.0 breakdown voltage, dc **Current Rating Per Characteristic:** 60.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Weapon system essential **Precious Material And Location:** Solder tab plated gold **Test Data Document:** 95542-941-032 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 solder stud and 1 tab, solder lug and 1 threaded stud

--

N/a

Shelf Life:

Unit Of Measure:

NSN 5961-00-139-6630

Diode Semiconductor Device - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A110a0